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## **Supporting Information**

## Porous copper-graphene heterostructures for cooling of electronic devices

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Figure S1. C1 XPS spectra of Cu and GO mixture before (black) and after (red) thermal treatment at 1000 °C.



Figure S2. BET of pCu and pCu-rGO.



Figure S3. Thermal diffusivity, heat capacity and calculated thermal conductivity of bulk Cu(top), pCu(mid) and pCu-rGO(bottom).



Figure S4. Simulated temperature distribution by convection heat transfer based on cellular energy-transport model. (top) bulk Cu, (mid) pCu, and (bottom) pCu-rGO with saturated at100 °C was naturally cooled down for same time at room temperature (20°C). Analysis model consists of three domains including air, rGO, and copper. Heat transferred by convection can be calculated using the equation;  $Q = H_c \times A \times \Delta T/d \times t$ , where Q is the provided heat, Hc is the convection heat transfer coefficient, A is the cross sectional area, T is the temperature difference, and d is the thickness of material.